

General Description

The XL236-2.5 / XL336-2.5 and XT336-2.5 integrated circuits are precision 2.5V shunt regulator diodes. These monolithic IC voltage references operate as a low-temperature-coefficient 2.5V zener with 0.2 Ω dynamic impedance. A third terminal on the XL236-2.5 allows the reference voltage and temperature coefficient to be trimmed easily.

The XL236-2.5 series is useful as a precision 2.5V low voltage reference for digital voltmeters, power supplies or op amp circuitry. The 2.5V make it convenient to obtain a stable reference from 5V logic supplies. Further, since the XL236-2.5 operates as a shunt regulator, it can be used as either a positive or negative voltage reference.

The XL236-2.5 is rated for operation over -55° C to $+125^{\circ}$ C while the XL336-2.5 is rated over a -25° C to $+85^{\circ}$ C temperature range.

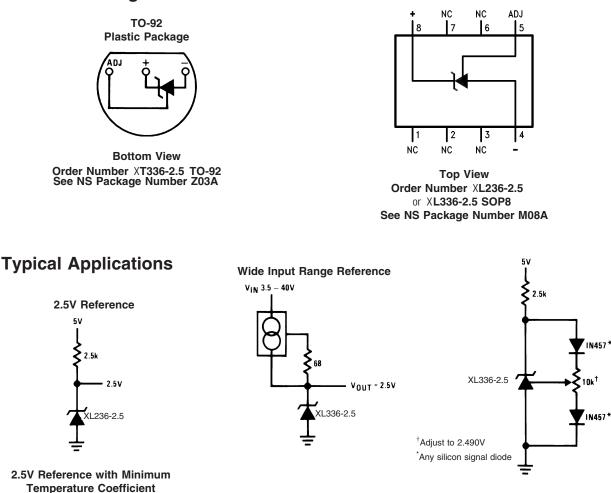
The XT336-2.5 is rated for operation over a 0°C to +70°C temperature range. See the connection diagrams for available packages.

SO Package

Features

- Low temperature coefficient
- Wide operating current of 400 µA to 10 mA
- 0.2Ω dynamic impedance
- ±1% initial tolerance available
- Guaranteed temperature stability
- Easily trimmed for minimum temperature drift
- Fast turn-on

Connection Diagrams



Absolute Maximum Ratings (Note 1)

Reverse Current	15 mA
Forward Current	10 mA
Storage Temperature	–60°C to +150°C
Operating Temperature Range (Note 2)	
XL236	–55°C to +150°C
XL336	–25°C to +85°C

XT336	0°C to +70°C
Soldering Information	
TO-92 Package (10 sec.)	260°C
TO-46 Package (10 sec.)	300°C
SO Package	
Vapor Phase (60 sec.)	215°C
Infrared (15 sec.)	220°C
See AN-450 "Surface Mounting Meth	ods and Their Effect

See AN-450 "Surface Mounting Methods and Their Effect on Product Reliability" (Appendix D) for other methods of soldering surface mount devices.

Electrical Characteristics (Note 3)

Parameter	Conditions	XL236-2.5/XL336-2.5		2.5	XT 336-2.5			Units
		Min	Тур	Max	Min	Тур	Max	
Reverse Breakdown	T _A =25°C, I _R =1 mA							
Voltage	XL236-2.5 XL336-2.5	2.440	2.490	2.540	2.390	2.490	2.590	V
	XT336-2.5	2.465	2.490	2.515	2.440	2.490	2.540	V
Reverse Breakdown	T _A =25°C,		2.6	6		2.6	10	mV
Change								
With Current	400 µA≤I _R ≤10 mA							
Reverse Dynamic	$T_A=25^{\circ}C$, $I_R=1$ mA, f = 100 Hz		0.2	0.6		0.2	1	Ω
Impedance								
Temperature Stability	V _R Adjusted to 2.490VI _R =1							
(Note 4)	mA, <i>Figure 2</i> 0°C≤T _A ≤70°C							
	(XL336)–25°C≤T _A ≤+85°C					1.8	6	mV
	XL336,XT336		3.5	9				mV
	$-25^{\circ}C \le T_{A} \le +85^{\circ}C \text{ (XL336M)}$							
	–55°C≤T _A ≤+125°C XL236		7.5	18				mV
			12	18				mV
Reverse Breakdown	400 µA≤I _R ≤10 mA		3	10		3	12	mV
Change								
With Current								
Reverse Dynamic	I _R =1 mA		0.4	1		0.4	1.4	Ω
Impedance								
Long Term Stability	$T_A=25^{\circ}C \pm 0.1^{\circ}C, I_B=1 \text{ mA},$		20			20		ppm
	t = 1000 hrs							

Note 1: Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Electrical specifications do not apply when operating the device beyond its specified operating conditions.

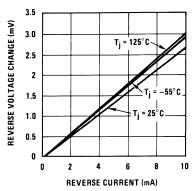
Note 2: For elevated temperature operation, T_j max is:

XL236	150°C
XL336	125°C
XT336	100°C

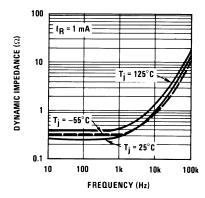
Thermal Resistance	TO-92	TO-46	SO-8
θ_{ja} (Junction to Ambient)	180°C/W (0.4" leads)	440°C/W	165°C/W
	170°C/W (0.125" lead)		
θ_{ja} (Junction to Case)	n/a	80°C/W	n/a

Typical Performance Characteristics

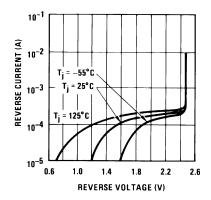






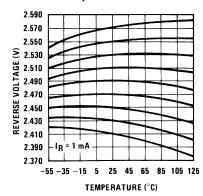


Reverse Characteristics

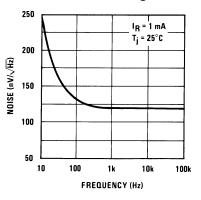


Typical Performance Characteristics (Continued)

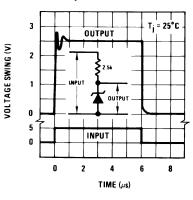
Temperature Drift



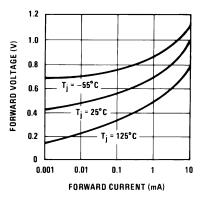




Response Time



Forward Characteristics



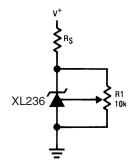


FIGURE 1. XL236 With Pot for Adjustment of Breakdown Voltage (Trim Range = ±120 mV typical)

Application Hints

The XL236 series voltage references are much easier to use than ordinary zener diodes. Their low impedance and wide operating current range simplify biasing in almost any circuit. Further, either the breakdown voltage or the temperature coefficient can be adjusted to optimize circuit performance.

Figure 1 shows an XL236 with a 10k potentiometer for adjusting the reverse breakdown voltage. With the addition of R1 the breakdown voltage can be adjusted without affecting the temperature coefficient of the device. The adjustment range is usually sufficient to adjust for both the initial device tolerance and inaccuracies in buffer circuitry.

If minimum temperature coefficient is desired, two diodes can be added in series with the adjustment potentiometer as shown in *Figure 2*. When the device is adjusted to 2.490V the temperature coefficient is minimized. Almost any silicon signal diode can be used for this purpose such as a 1N914, 1N4148 or a 1N457. For proper temperature compensation the diodes should be in the same thermal environment as the XL236. It is usually sufficient to mount the diodes near the XL236 on the printed circuit board. The absolute resistance of R1 is not critical and any value from 2k to 20k will work.

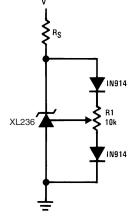
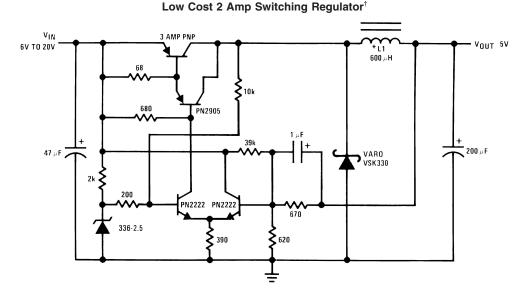


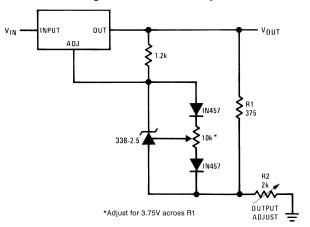
FIGURE 2. Temperature Coefficient Adjustment (Trim Range = ±70 mV typical)

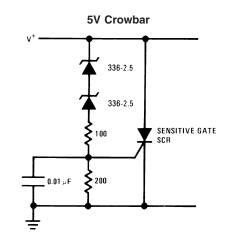
Application Hints (Continued)

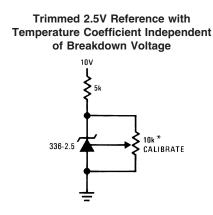


^{*}L1 60 turns #16 wire on Arnold Core A-254168-2 [†]Efficiency \approx 80%

Precision Power Regulator with Low Temperature Coefficient

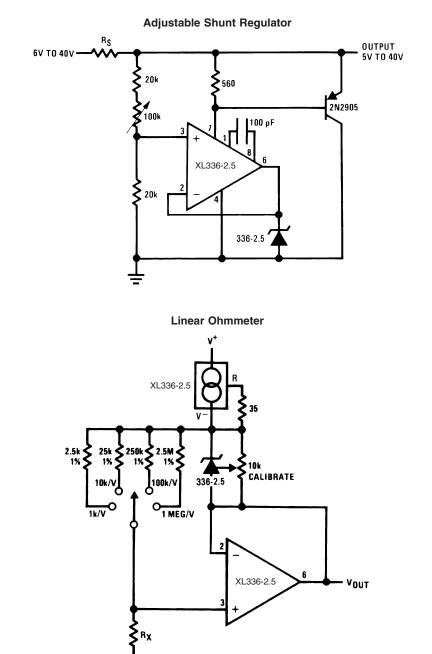




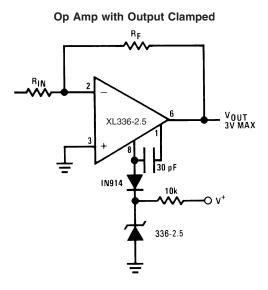


*Does not affect temperature coefficient

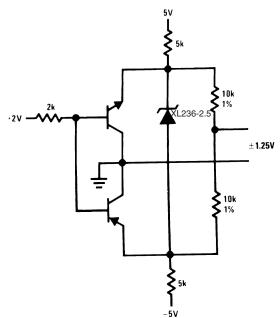
Application Hints (Continued)



Application Hints (Continued)

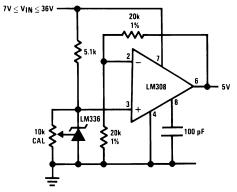


Bipolar Output Reference

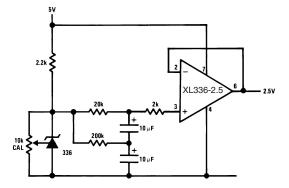


2.5V Square Wave Calibrator

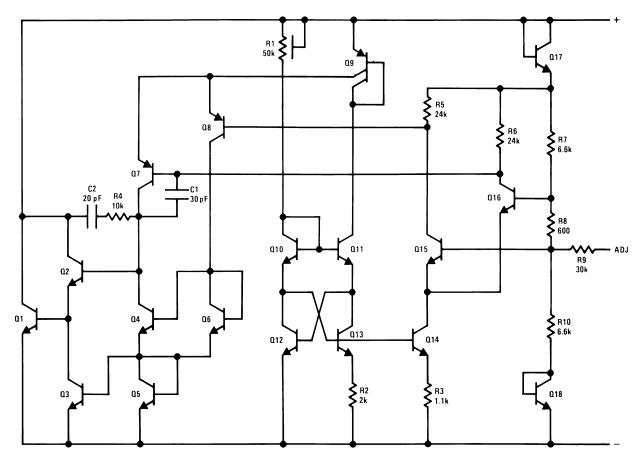




Low Noise Buffered Reference



Schematic Diagram



以上信息仅供参考.如需帮助联系客服人员。谢谢 XINLUDA